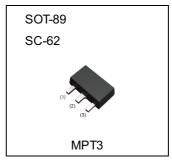


#### NPN 100mA 400V Middle Power Transistor

Parameter	Value
V <sub>CEO</sub>	400V
IC	100mA

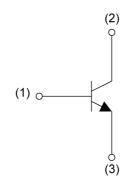
## Outline



### Features

1)Complementary PNP Types:2SAR340P
2)Low V<sub>CE(sat)</sub>
V<sub>CE(sat)</sub>=300mV(Max)
(I<sub>C</sub>/I<sub>B</sub>=20mA/2mA)

### ●Inner circuit



- (1) Base
- (2) Collector
- (3) Emitter

### Application

LOW FREQUENCY AMPLIFIER

## Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SCR346P	SOT-89 (MPT3)	4540	T100	180	12	1000	HK

# ● Absolute maximum ratings (T<sub>a</sub> = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	$V_{CBO}$	400	V
Collector-emitter voltage	V <sub>CEO</sub>	400	V
Emitter-base voltage	V <sub>EBO</sub>	7	V
Calle atom a vision at	I <sub>C</sub>	100	mA
Collector current	I <sub>CP</sub> *1	200	mA
Base current	I <sub>B</sub>	30	mA
Daniel dia dia attan	P <sub>D</sub> *2	0.5	W
Power dissipation	P <sub>D</sub> *3	2.0	W
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

## ● Electrical characteristics (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = 100μA	400	-	1	V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1mA	400	1	1	<b>V</b>
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 100μA	7	1	1	٧
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 400V	ı	ı	10	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 6V	ı	ı	10	μA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 20 \text{mA}, I_B = 2 \text{mA}$	ı	100	300	mV
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA	82	ı	270	-
Output capacitance	C <sub>ob</sub>	$V_{CB} = 10V, I_{E} = 0A,$ f = 1MHz	1	6	1	pF

## hFE values are calssified as follows:

rank	Р	Q	-	-	-
h <sub>FE</sub>	82-180	120-270	-	-	-

<sup>\*1</sup> Pw=10ms Single Pulse

<sup>\*2</sup> Each terminal mounted on a reference land.

<sup>\*3</sup> Mounted on a 40×40×0.7mm ceramic board.

## ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.1 Grounded Emitter Propagation Characteristics

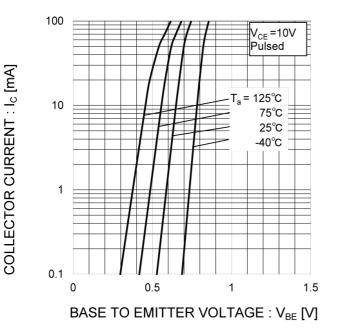
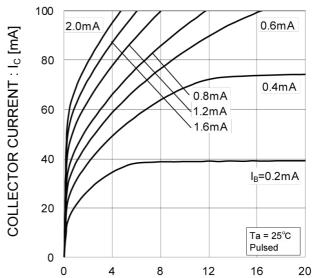


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V<sub>CE</sub> [V]

Fig.3 DC Current Gain vs Collector Current(I)

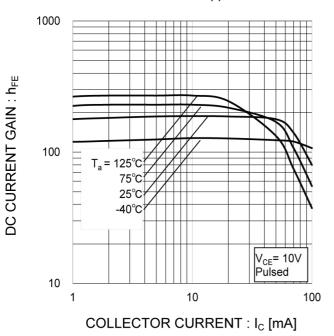
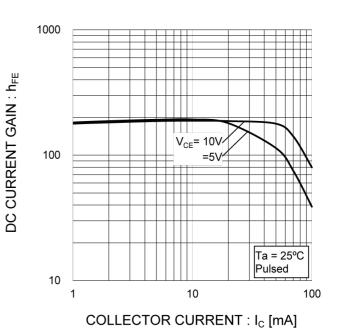


Fig.4 DC Current Gain vs Collector Current(II)



## ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs.Collector-Emitter Saturation Voltage vs. Collector Current( I )

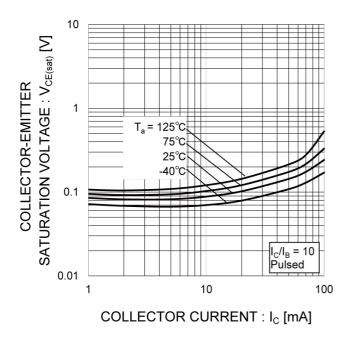


Fig.6 Collector-Emitter Saturation Voltage vs.Collector-Emitter Saturation Voltage vs. Collector Current(II)

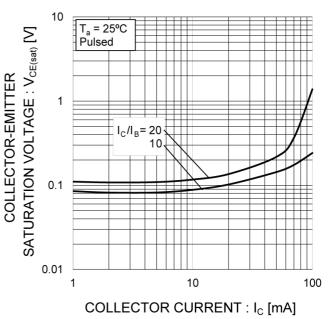


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

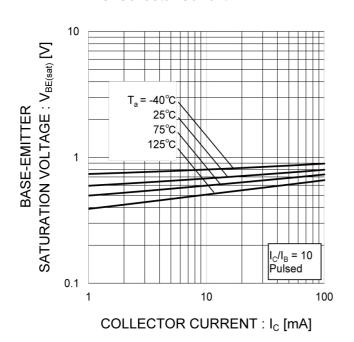
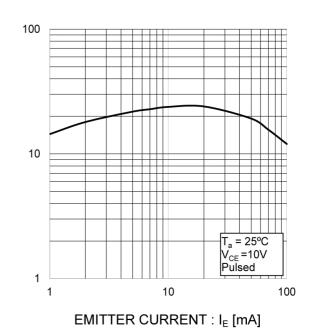


Fig.8 Gain Bandwidth Product vs. Emitter Current



TRANSITION FREQUENCY : fr [MHz]

COLLECTOR OUTPUT CAPACITANCE : C<sub>ob</sub> [pF] EMITTER INPUT CAPACITANCE : C<sub>ib</sub> [pF]

10

= 25°C

10

COLLECTOR-BASE VOLTAGE: V<sub>CB</sub> [V]

EMITTER-BASE VOLTAGE: VEB [V]

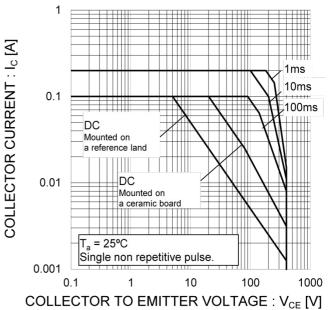
= 1MHz == 0A == 0A

## ● Electrical characteristic curves(T<sub>a</sub> = 25°C)

Fig.9 Emitter input capacitance
vs. Emitter-Base Voltage
Collector output capacitance
vs. Collector-Base Voltage

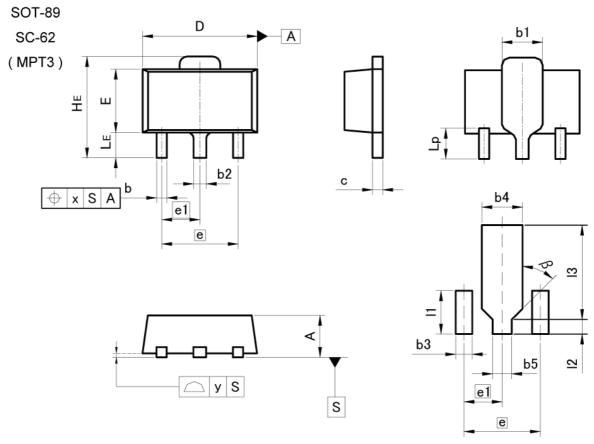
C<sub>ib</sub>

Fig.10 Safe Operating Area



ROHM

## Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
Ь	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
Е	2.40	2.70	0.094	0.106	
е	3.00		0.118		
e1	1.	50	0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
X	0-0	0.15	-	0.006	
У	-	0.10	_	0.004	

DIM	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b3	-	0.65	-	0.026	
b4	_	1.70	1	0.067	
b5	3-3	0.75		0.030	
11	_	1.71		0.067	
12	-	0.58	-	0.023	
13	_	3.72	_	0.146	
β	45	0	45°		

Dimension in mm/inches



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